



MBRF2030CT thru MBRF20150CT

SCHOTTKY BARRIER RECTIFIERS

REVERSE VOLTAGE - 30 to 150Volts
FORWARD CURRENT - 20.0 Amperes

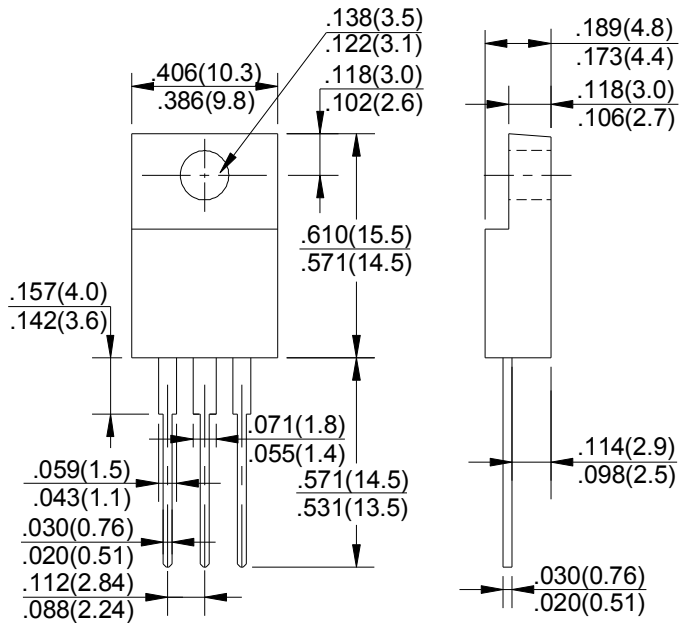
FEATURES

- Metal of silicon rectifier , majority carrier conduction
- Guard ring for transient protection
- Low power loss,high efficiency
- High current capability,low VF
- High surge capacity
- Plastic package has UL flammability classification 94V-0
- For use in low voltage,high frequency inverters,free wheeling,and polarity protection applications

MECHANICAL DATA

- Case: ITO-220AB molded plastic
- Polarity: As marked on the body
- Weight: 0.08ounces,2.24 grams
- Mounting position :Any

ITO-220AB



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25°C ambient temperature unless otherwise specified.

Single phase, half wave ,60Hz, resistive or inductive load.

For capacitive load, derate current by 20%

CHARACTERISTICS	SYMBOL	MBRF 2030CT	MBRF 2040CT	MBRF 2050CT	MBRF 2060CT	MBRF 2080CT	MBRF 20100CT	MBRF 20150CT	UNIT
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	30	40	50	60	80	100	150	V
Maximum RMS Voltage	V _{RMS}	21	28	35	42	56	70	105	V
Maximum DC Blocking Voltage	V _{DC}	30	40	50	60	80	100	150	V
Maximum Average Forward Rectified Current (See Fig.1)	I <sub(av)< sub=""></sub(av)<>	20.0							A
Peak Forward Surge Current 8.3ms Single Half Sine-Wave Super Imposed on Rated Load (JEDEC Method)	I _{FSM}	150							A
Peak Forward Voltage (Note1)	V _F								V
IF=10A @T _J =25°C		-		0.80		0.85		0.95	
IF=10A @T _J =125°C		0.57		0.70		0.75		0.85	
IF=20A @T _J =25°C		0.84		0.95		0.95		1.05	
IF=20A @T _J =125°C		0.72		0.85		0.85		0.95	
Maximum DC Reverse Current at Rated DC Bolcking Voltage	I _R								mA
@T _J =25°C		0.1		0.1		0.1		0.1	
@T _J =125°C		15		10		7.5		5.0	
Typical Junction Capacitance (Note2)	C _J	400	320						pF
Typical Thermal Resistance (Note3)	R _{θJC}	1.5				3.5			°C/W
Operating Temperature Range	T _J	-55 to +150							°C
Storage Temperature Range	T _{STG}	-55 to +175							°C

NOTES:1.300us pulse width,2% duty cycle.

2.Measured at 1.0 MHz and applied reverse voltage of 4.0V DC.

3.Thermal resistance junction to case.

RATING AND CHARACTERISTIC CURVES
MBRF2030CT thru MBRF20150CT



FIG. 1 – FORWARD CURRENT DERATING CURVE

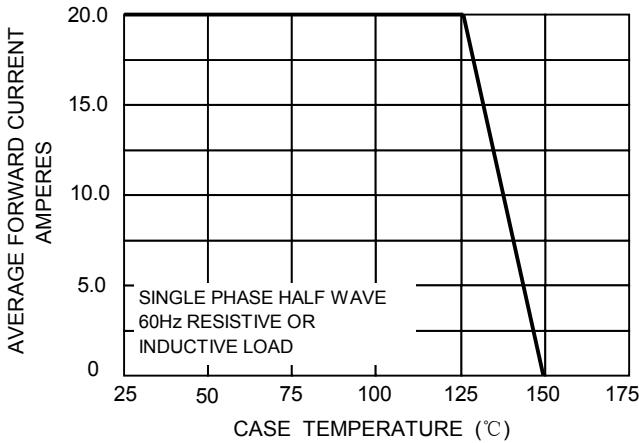


FIG. 2 – MAXIMUM NON-REPETITIVE SURGE CURRENT

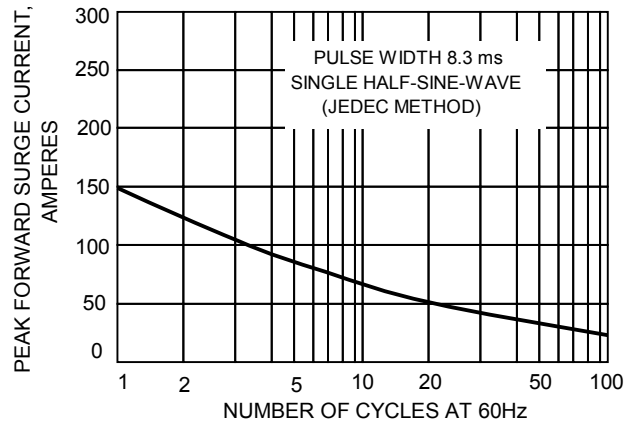


FIG.3-TYPICAL REVER CHARACTERISTICS

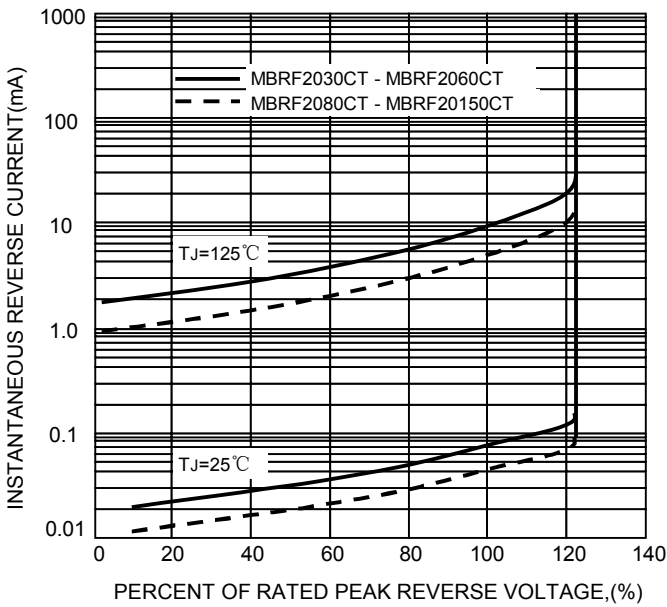


FIG.4-TYPICAL FORWARD CHARACTERISTICS

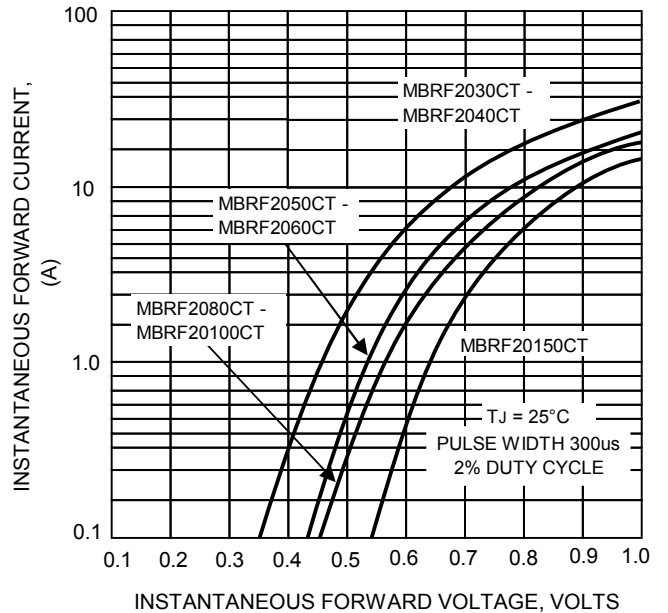


FIG.5 – TYPICAL JUNCTION CAPACITANCE

